

Serial EEPROM Series Standard EEPROM WLCSP EEPROM

BRCA016GWZ-W (16Kbit)

General Description

BRCA016GWZ-W series is a serial EEPROM of I²C BUS Interface Method.

Features

- Completely conforming to the world standard I²C BUS. All controls available by 2 ports of serial clock (SCL) and serial data (SDA)
- Other devices than EEPROM can be connected to the same port, saving microcontroller port.
- 1.7V to 3.6V Single Power Source Operation most suitable for battery use.
- Possible FAST MODE 400KHz operation
- Page Write Mode useful for initial value write at factory shipment.
- Self-timed Programming Cycle
- Low Current Consumption
 - At Write Operation (5V) : 0.5mA (Typ)
 - At Read Operation (5V) : 0.2mA (Typ)
 - At Standby Operation (5V) : 0.1μA (Typ)
- Prevention of Write Mistake
 - Write (write protect) function added
 - Prevention of write mistake at low voltage
- UCSP30L1 Compact Package
 - W(Typ) x D(Typ) x H(Max) : 1.30mm x 0.77mm x 0.35mm
- More than 1 million write cycles
- More than 40 years data retention
- Noise Filter Built in SCL / SDA terminal
- Initial Delivery State FFh

BRCA016GWZ-W

Capacity	Bit Format	Type	Power Source Voltage	Package
16Kbit	2K×8	BRCA016GWZ-W	1.7V to 3.6V	UCSP30L1

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limit	Unit	Remark
Supply Voltage	V _{CC}	-0.3 to +6.5	V	
Permissible Dissipation	P _d	220	mW	Derate by 2.2mW/°C when operating above Ta=25°C
Storage Temperature	T _{stg}	-65 to +125	°C	
Operating Temperature	T _{opr}	-40 to +85	°C	
Input Voltage/ Output Voltage	-	-0.3 to V _{CC} +1.0	V	

Memory Cell Characteristics (Ta=25°C, V_{CC}=1.7V to 3.6V)

Parameter	Limit			Unit
	Min	Typ	Max	
Write Cycles ⁽¹⁾	100,000	-	-	Times
Data Retention ⁽¹⁾	40	-	-	Years

(1) Not 100% TESTED

○Product structure : Silicon monolithic integrated circuit ○This product has no designed protection against radioactive rays

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Recommended Operating Ratings

Parameter	Symbol	Limit	Unit
Power Source Voltage	V _{CC}	1.7 to 3.6	V
Input Voltage	V _{IN}	0 to V _{CC}	

DC Characteristics

(Unless otherwise specified, Ta=-40°C to +85°C, V_{CC}=1.7V to 3.6V)

Parameter	Symbol	Limit			Unit	Conditions
		Min	Typ	Max		
Input High Voltage1	V _{IH1}	0.7V _{CC}	-	V _{CC} +1.0	V	
Input Low Voltage1	V _{IL1}	-0.3	-	+0.3V _{CC}	V	
Output Low Voltage1	V _{OL1}	-	-	0.4	V	I _{OL} =3.0mA, 2.5V ≤ V _{CC} ≤ 3.6V (SDA)
Output Low Voltage2	V _{OL2}	-	-	0.2	V	I _{OL} =0.7mA, 1.7V ≤ V _{CC} ≤ 2.5V (SDA)
Input Leakage Current	I _{LI}	-1	-	+1	μA	V _{IN} =0 to V _{CC}
Output Leakage Current	I _{LO}	-1	-	+1	μA	V _{OUT} =0 to V _{CC} (SDA)
Supply Current (Write)	I _{CC1}	-	-	2.0	mA	V _{CC} =3.6V, f _{SCL} =400kHz, t _{WR} =5ms Byte Write, Page Write
Supply Current (Read)	I _{CC2}	-	-	0.5	mA	V _{CC} =3.6V, f _{SCL} =400kHz Random Read, Current Read, Sequential Read
Standby Current	I _{SB}	-	-	2.0	μA	V _{CC} =3.6V, SDA = SCL=V _{CC} A0, A1, A2=GND, WP=GND

AC Characteristics

(Unless otherwise specified, Ta=-40°C to +85°C, V_{CC}=1.7V to 3.6V)

Parameter	Symbol	Limit			Unit
		Min	Typ	Max	
Clock Frequency	f _{SCL}	-	-	400	kHz
Data Clock High Period	t _{HIGH}	0.6	-	-	μs
Data Clock Low Period	t _{LOW}	1.2	-	-	μs
SDA, SCL Rise Time ⁽¹⁾	t _R	-	-	0.3	μs
SDA, SCL Fall Time ⁽¹⁾	t _F	-	-	0.3	μs
Start Condition Hold Time	t _{HD:STA}	0.6	-	-	μs
Start Condition Setup Time	t _{SU:STA}	0.6	-	-	μs
Input Data Hold Time	t _{HD:DAT}	0	-	-	ns
Input Data Setup Time	t _{SU:DAT}	100	-	-	ns
Output Data Delay Time	t _{PD}	0.1	-	0.9	μs
Output Data Hold Time	t _{DH}	0.1	-	-	μs
Stop Condition Setup Time	t _{SU:STO}	0.6	-	-	μs
Bus Free Time	t _{BUF}	1.2	-	-	μs
Write Cycle Time	t _{WR}	-	-	5	ms
Noise Spike Width(SDA,SCL terminal)	t _I	-	-	0.1	μs
WP Hold Time	t _{HD:WP}	1.0	-	-	μs
WP Setup Time	t _{SU:WP}	0.1	-	-	μs
WP High Period	t _{HIGH:WP}	1.0	-	-	μs

(1) Not 100% TESTED

Serial Input / Output Timing

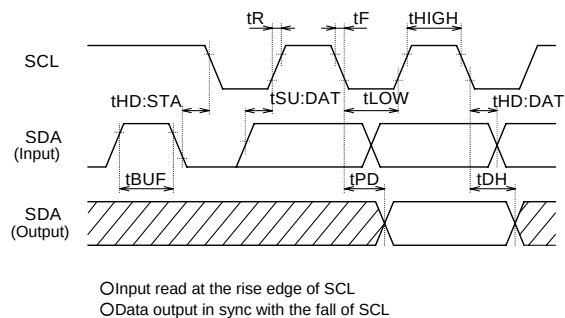


Figure 1-(a). Serial Input / Output Timing

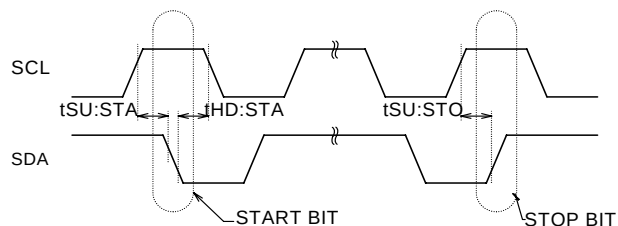


Figure 1-(b). Start - Stop Bit Timing

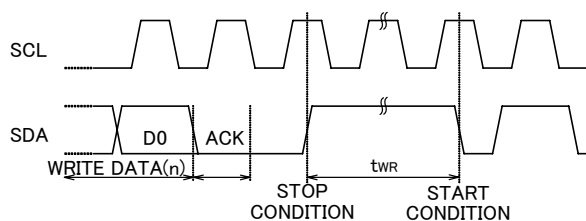


Figure 1-(c). Write Cycle Timing

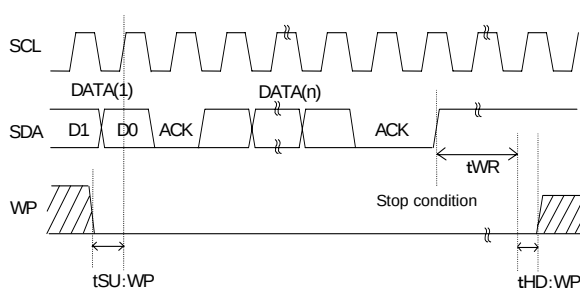
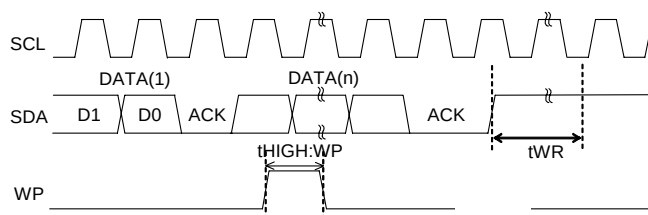


Figure 1-(d). WP Timing at Write Execution



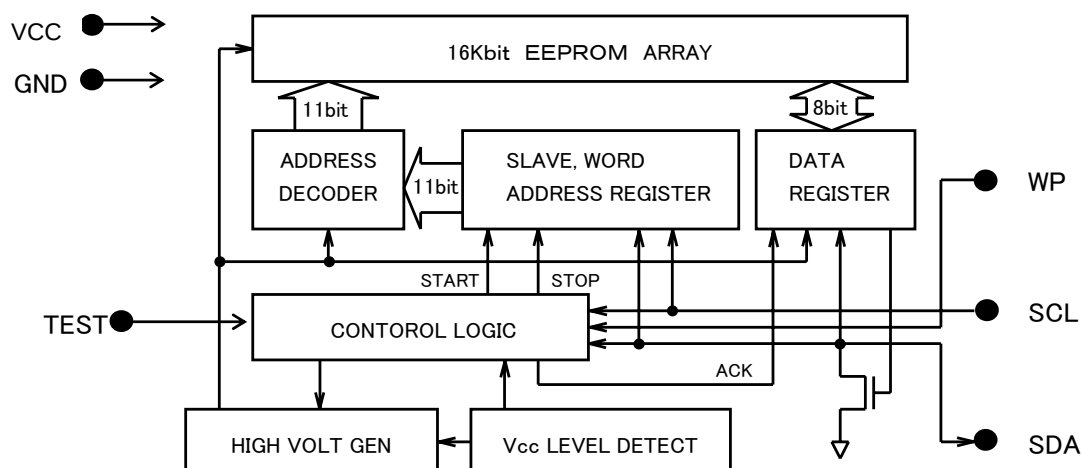
OAt write execution, in the area from the D0 taken clock rise of the first DATA(1), to t_{WR} , set WP = 'LOW'.

OBy setting WP "HIGH" in the area, write can be cancelled.

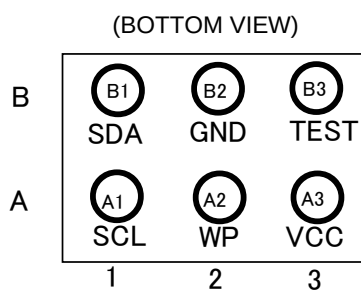
When it is set WP = 'HIGH' during t_{WR} , write is forcibly ended, and data of address under access is not guaranteed, therefore write it once again.

Figure 1-(e). WP Timing at Write Cancel

Block Diagram



Pin Configuration



Pin Descriptions

Land No.	Pin Name	I/O	Descriptions
B3	TEST	Input	TEST terminal, connect to GND
B2	GND	-	Ground (0V)
B1	SDA	Input, Output	Slave word address Serial data input Serial data output
A3	VCC	-	Power supply
A2	WP	Input	Write protect
A1	SCL	Input	Serial clock input

Typical Performance Curves

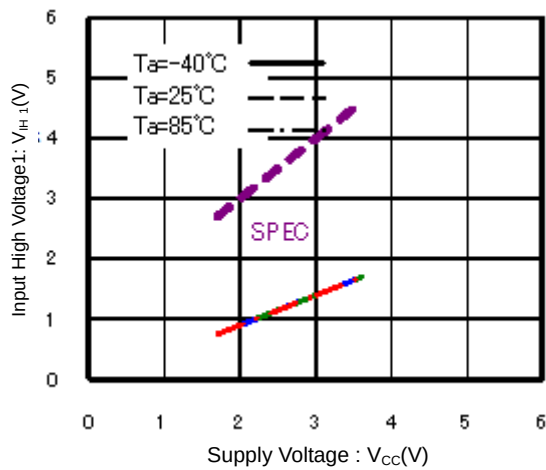


Figure 2. Input High Voltage1 vs Supply Voltage (SCL,SDA,WP)

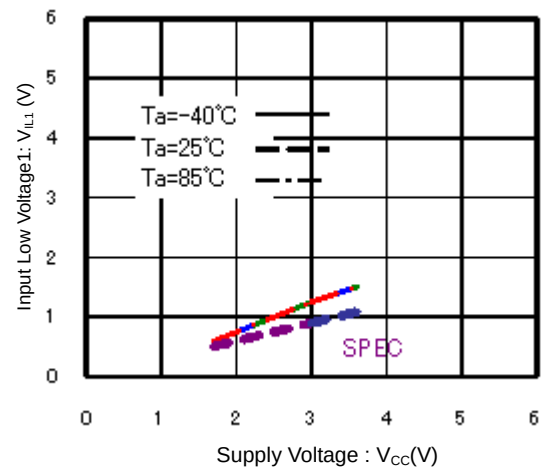


Figure 3. Input Low Voltage1 vs Supply Voltage (SCL,SDA,WP)

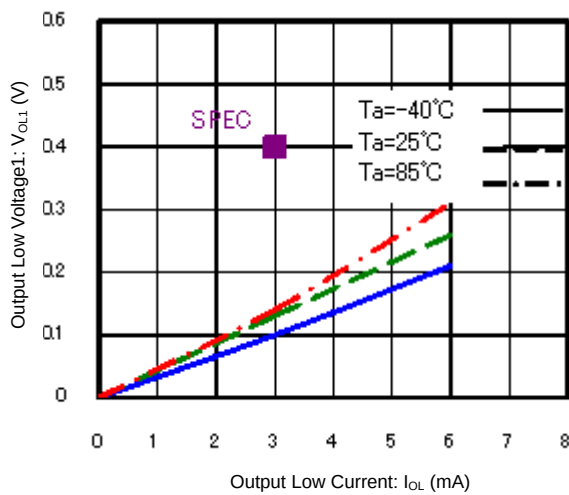


Figure 4. Output Low Voltage1 vs Output Low Current ($V_{CC} = 2.5\text{V}$)

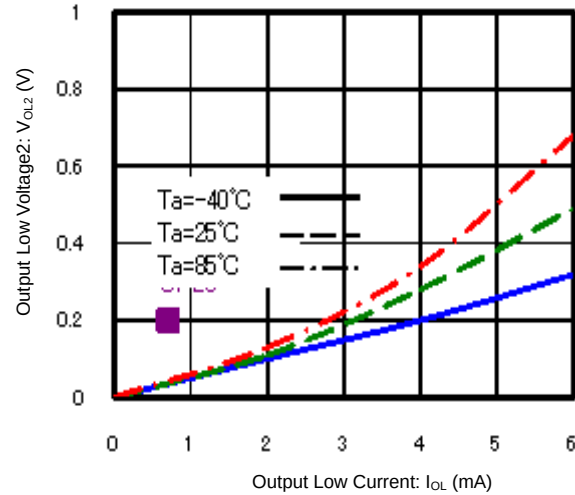


Figure 5. Output Low Voltage2 vs Output Low Current ($V_{CC} = 1.7\text{V}$)

Typical Performance Curves – Continued

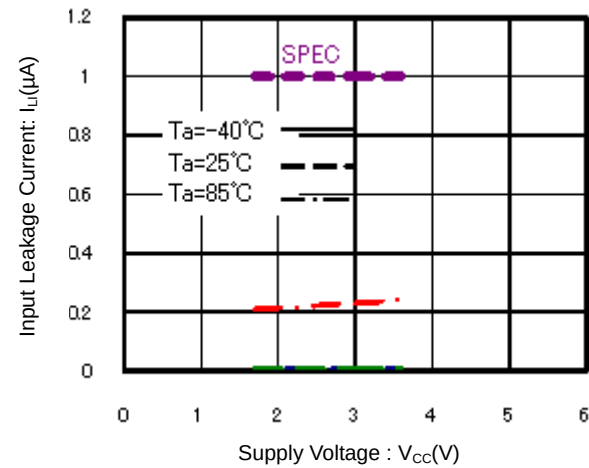


Figure 6. Input Leakage Current vs Supply Voltage (SCL, WP)

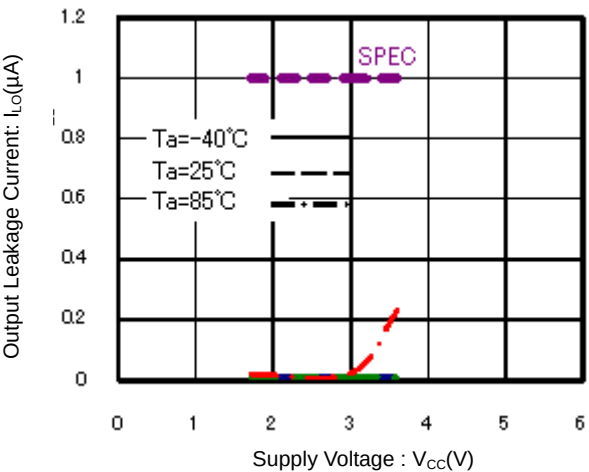


Figure 7. Output Leakage Current vs Supply Voltage (SDA)

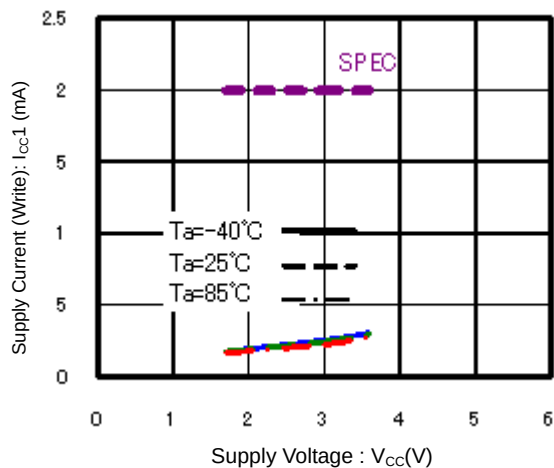


Figure 8. Supply Current (Write) vs Supply Voltage ($f_{SCL}=400kHz$)

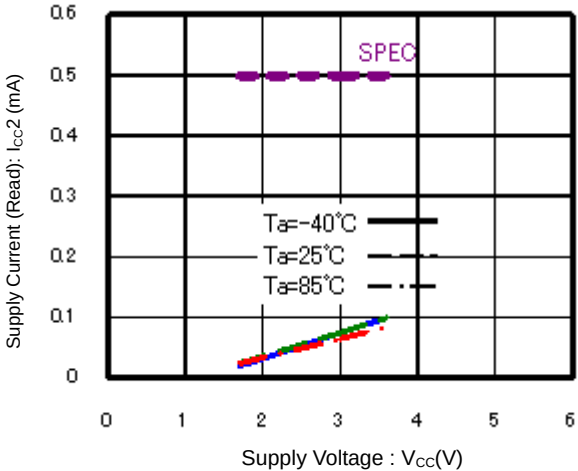


Figure 9. Supply Current (Read) vs Supply Voltage ($f_{SCL}=400kHz$)

Typical Performance Curves – Continued

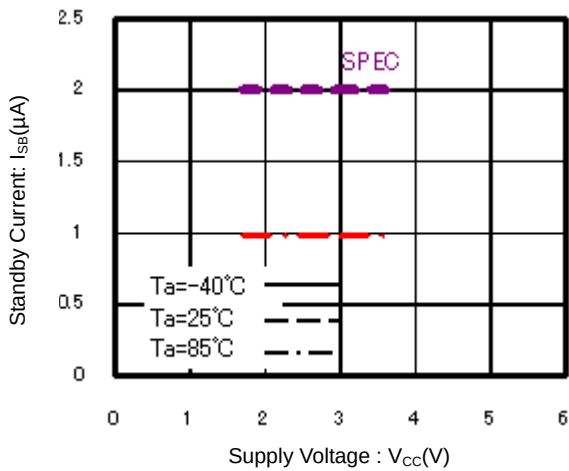


Figure 10. Standby Current vs Supply Voltage

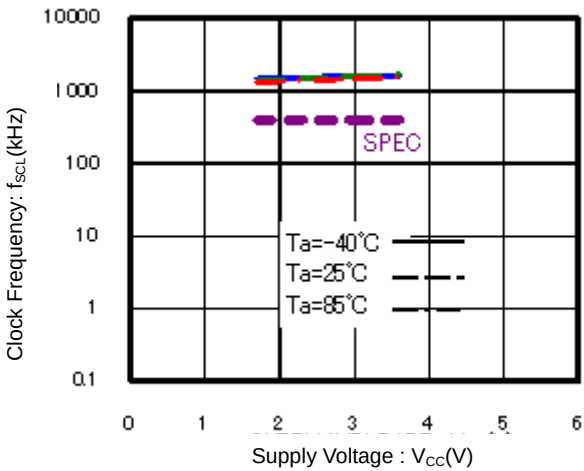


Figure 11. Clock Frequency vs Supply Voltage

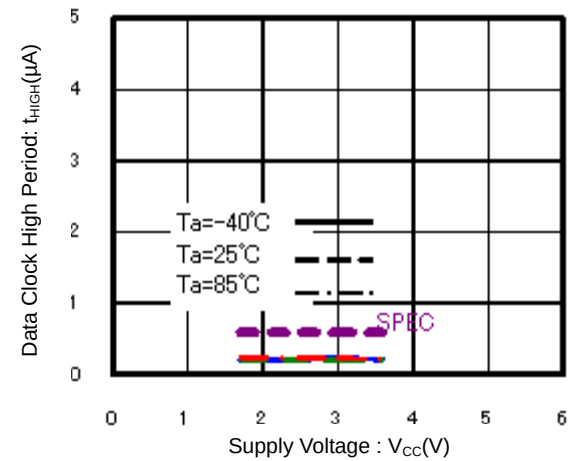


Figure 12. Data Clock High Period vs Supply Voltage

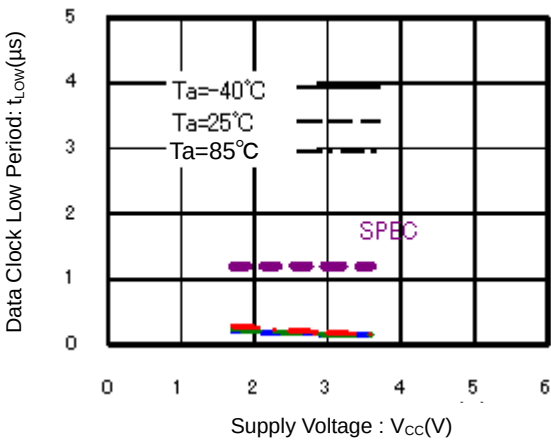


Figure 13. Data Clock Low Period vs Supply Voltage

Typical Performance Curves – Continued

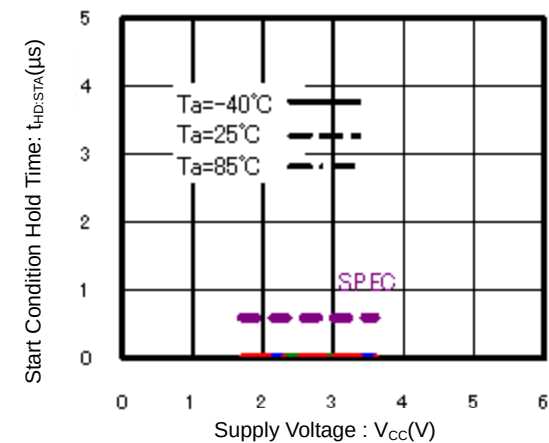


Figure 14. Start Condition Hold Time vs Supply Voltage

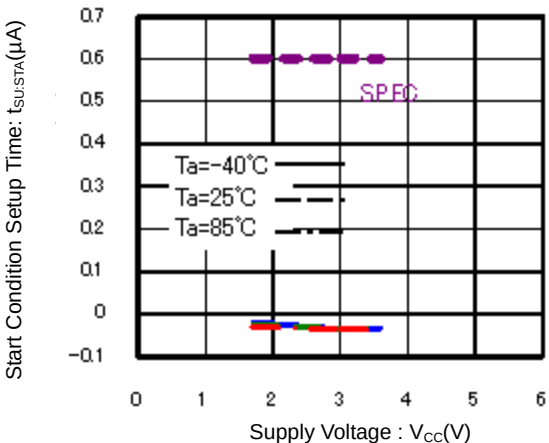


Figure 15. Start Condition Setup Time vs Supply Voltage

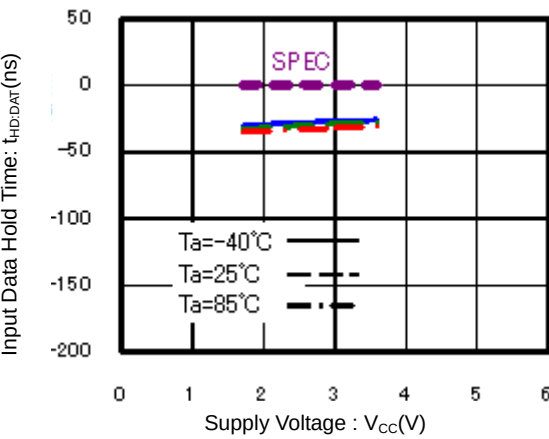


Figure 16. Input Data Hold Time vs Supply Voltage

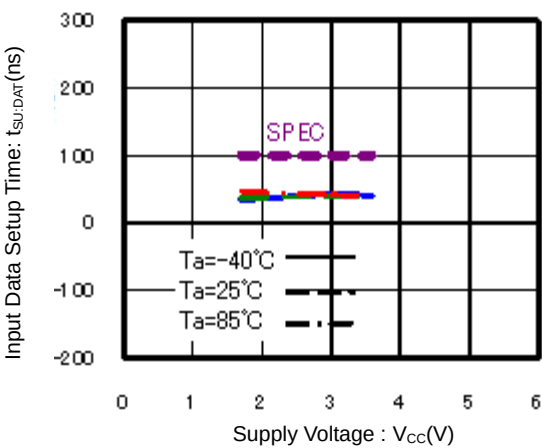


Figure 17. Input Data Setup Time vs Supply Voltage

Typical Performance Curves – Continued

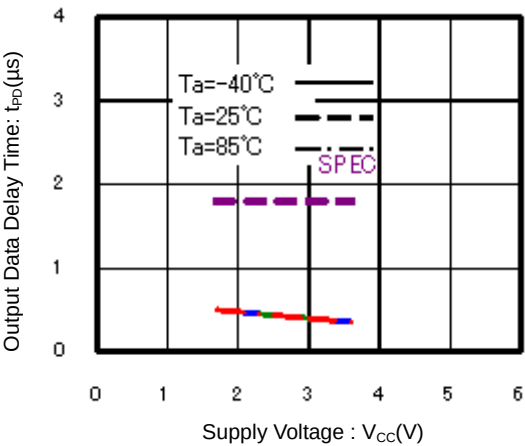


Figure 18. Output Data Delay Time vs Supply Voltage (LOW)

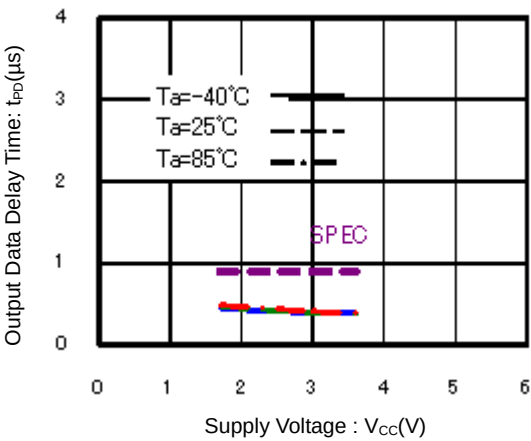


Figure 19. Output Data Delay Time vs Supply Voltage (HIGH)

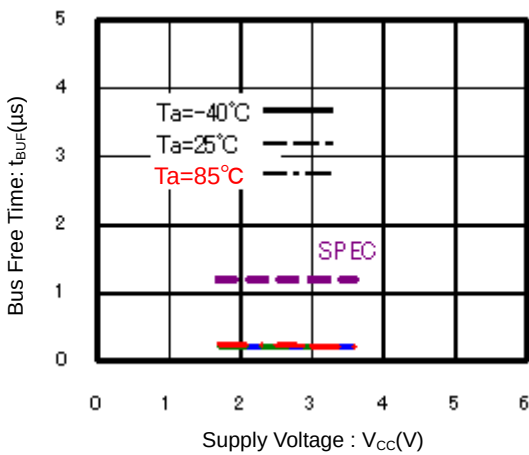


Figure 20. Bus Free Time vs Supply Voltage

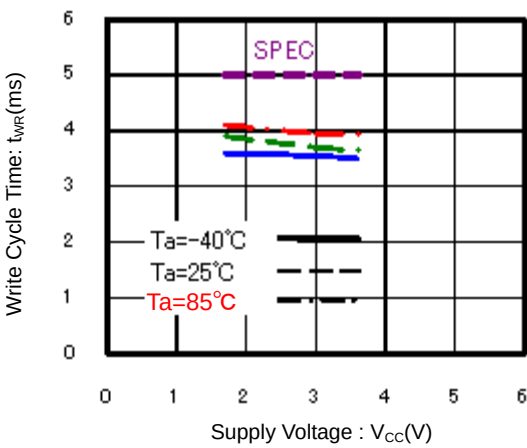


Figure 21. Write Cycle Time vs Supply Voltage

Typical Performance Curves – Continued

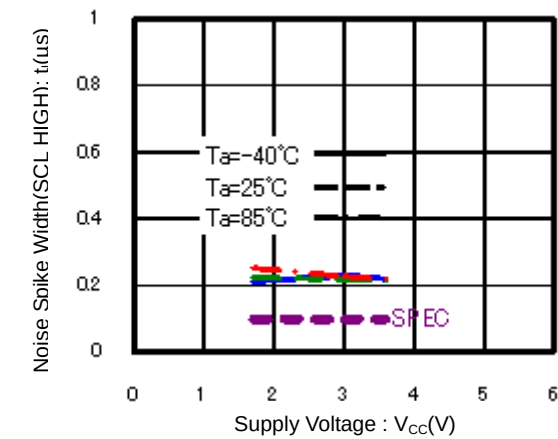


Figure 22. Noise Spike Width vs Supply Voltage (SCL HIGH)

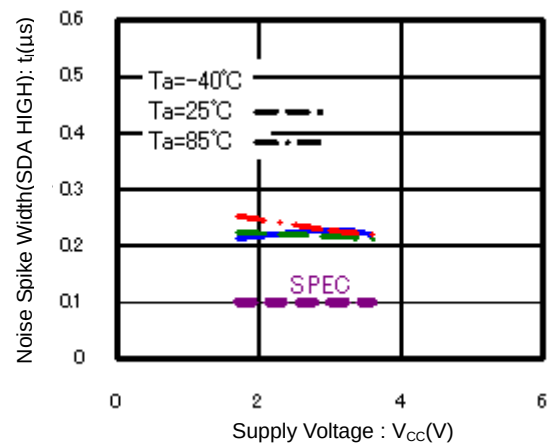


Figure 23. Noise Spike Width vs Supply Voltage (SDA HIGH)

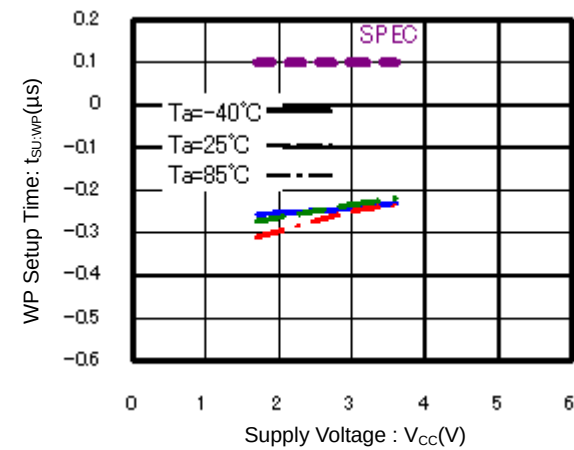


Figure 24. WP Setup Time vs Supply Voltage

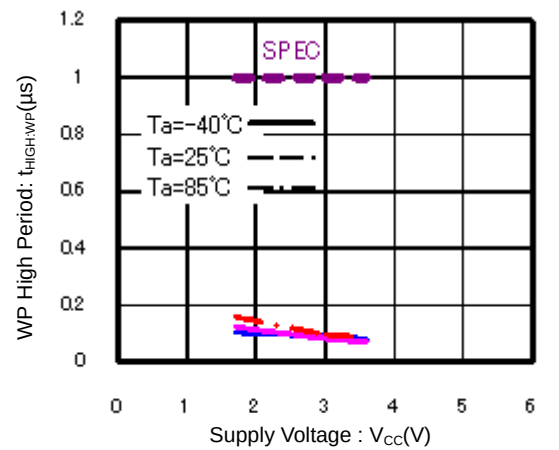


Figure 25. WP High Period vs Supply Voltage

Timing Chart

1. I²C BUS Data Communication

I²C BUS data communication starts by start condition input, and ends by stop condition input. Data is always 8bit long, and acknowledge is always required after each byte. I²C BUS data communication with several devices is possible by connecting with 2 communication lines: serial data (SDA) and serial clock (SCL).

Among the devices, there should be a "master" that generates clock and control communication start and end. The rest become "slave" which are controlled by an address peculiar to each device, like this EEPROM. The device that outputs data to the bus during data communication is called "transmitter", and the device that receives data is called "receiver".

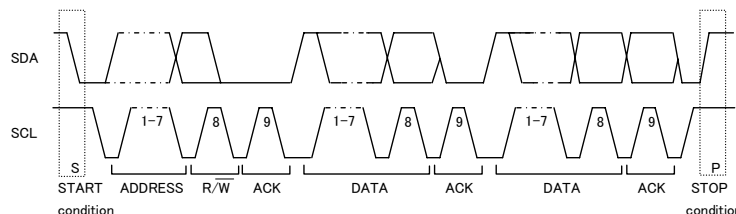


Figure 26. Data Transfer Timing

2. Start Condition (Start Bit Recognition)

- (1) Before executing each command, start condition (start bit) where SDA goes from 'HIGH' down to 'LOW' when SCL is 'HIGH' is necessary.
- (2) This IC always detects whether SDA and SCL are in start condition (start bit) or not, therefore, unless this condition is satisfied, any command cannot be executed.

3. Stop Condition (Stop Bit Recognition)

- (1) Each command can be ended by a stop condition (stop bit) where SDA goes from 'LOW' to 'HIGH' while SCL is 'HIGH'.

4. Acknowledge (ACK) Signal

- (1) The acknowledge (ACK) signal is a software rule to show whether data transfer has been made normally or not. In a master-slave communication, the device (Ex. μ -COM sends slave address input for write or read command, to this IC) at the transmitter (sending) side releases the bus after output of 8bit data.
- (2) The device (Ex. This IC receives the slave address input for write or read command from the μ -COM) at the receiver (receiving) side sets SDA 'LOW' during the 9th clock cycle, and outputs acknowledge signal (ACK signal) showing that it has received the 8bit data.
- (3) This IC, after recognizing start condition and slave address (8bit), outputs acknowledge signal (ACK signal) 'LOW'.
- (4) After receiving 8bit data (word address and write data) during each write operation, this IC outputs acknowledge signal (ACK signal) 'LOW'.
- (5) During read operation, this IC outputs 8bit data (read data) and detects acknowledge signal (ACK signal) 'LOW'. When acknowledge signal (ACK signal) is detected, and stop condition is not sent from the master (μ -COM) side, this IC continues to output data. When acknowledge signal (ACK signal) is not detected, this IC stops data transfer, recognizes stop condition (stop bit), and ends read operation. Then this IC becomes ready for another transmission.

5. Device Addressing

- (1) Slave address comes after start condition from master.
- (2) The significant 4 bits of slave address are used for recognizing a device type.
The device code of this IC is fixed to '1010'.
- (3) Next slave addresses (P2 P1 P0) are upper 3bit of word address, put these and word address (WA0 to WA7) together, 11bit word address (2048byte) of the device specified.
- (4) The most insignificant bit ($R/\overline{W}$ --- READ / WRITE) of slave address is used for designating write or read operation, and is as shown below.

Setting $R/\overline{W}$ to 0 ----- write (setting 0 to word address setting of random read)

Setting $R/\overline{W}$ to 1 ----- read

Type	Slave address	Maximum Number of Connected Buses
BRCA016GWZ-W	1 0 1 0 P2 P1 P0 $R/\overline{W}$	1

P0 to P2 are page select bits (Upper 3bit of word address).

Write Command

1. Write Cycle

- (1) Arbitrary data can be written to this EEPROM. When writing only 1 byte, Byte Write is normally used, and when writing continuous data of 2 bytes or more, simultaneous write is possible by Page Write cycle. The maximum number of bytes is specified per device of each capacity. Up to 16 arbitrary bytes can be written.

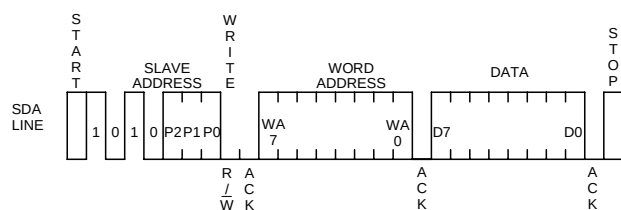


Figure 27. Byte Write Cycle

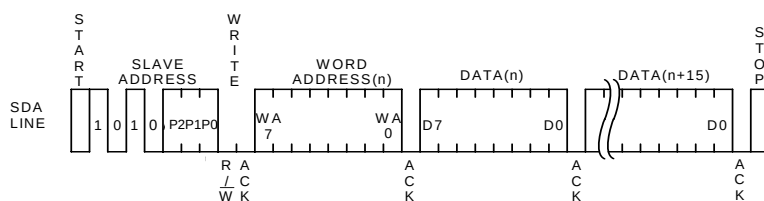


Figure 28. Page Write Cycle

- (2) Data is written to the address designated by word address (n-th address)
 (3) By issuing stop bit after 8bit data input, internal write to memory cell starts.
 (4) When internal write is started, command is not accepted for t_{WR} (5ms at maximum).
 (5) Using page write cycle, writing in bulk is done as follows: When data of more than 16bytes is sent, the byte in excess overwrites the data already sent first. (Refer to "Internal Address Increment" in Page 13.)

2. Notes on Write Cycle Continuous Input

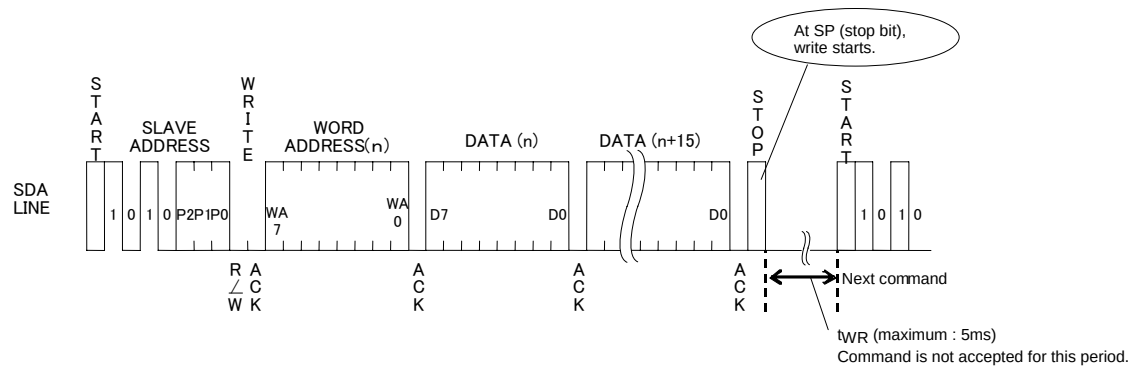


Figure 29. Page Write Cycle

3. Notes on Page Write Cycle

List of numbers of page write

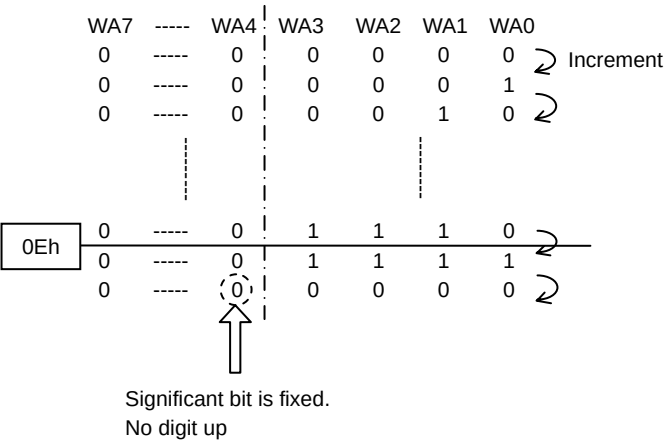
Number of Pages	16Byte
Product Number	BRCA016GWZ-W

The above numbers are maximum bytes for respective types.
Any bytes below these can be written.

In the case BRCA016GWZ-W, 1 page=16bytes, but the page write cycle write time is 5ms at maximum for 16byte bulk write.
It does not stand 5ms at maximum × 16byte=80ms (Max)

4. Internal Address Increment

Page Write Mode



For example, when it is started from address 0Eh, then, increment is made as below,
0Eh → 0Fh → 00h → 01h ---, please take note.
*0Eh...0E in hexadecimal, therefore, 00001110 becomes a binary number.

5. Write Protect (WP) Terminal

Write Protect (WP) Function

When WP terminal is set at Vcc (H level), data rewrite of all addresses is prohibited. When it is set at GND (L level), data rewrite of all address is enabled. Be sure to connect this terminal to Vcc or GND, or control it to H level or L level. Do not leave it open.

At extremely low voltage at power ON / OFF, by setting the WP terminal 'H', write error can be prevented.

Read Command

1. Read Cycle

Read cycle is when data of EEPROM is read. Read cycle could be random read cycle or current read cycle. Random read cycle is a command to read data by designating a specific address, and is used generally. Current read cycle is a command to read data of internal address register without designating an address, and is used when to verify just after write cycle. In both the read cycles, sequential read cycle is available where the next address data can be read in succession.

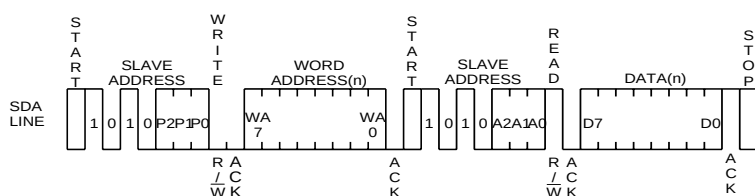


Figure 30. Random Read Cycle

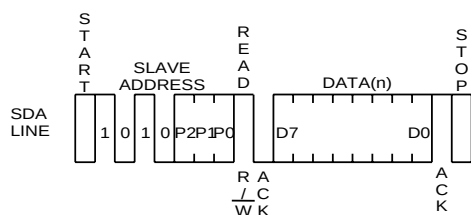


Figure 31. Current Read Cycle

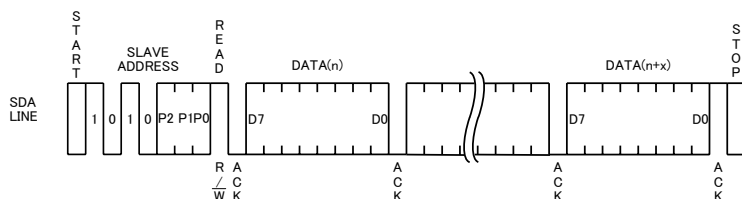


Figure 32. Sequential Read Cycle (in the case of Current Read Cycle)

- (1) In Random Read Cycle, data of designated word address can be read.
- (2) When the command just before current read cycle is random read cycle, current read cycle (each including sequential read cycle), data of incremented last read address (n)-th, i.e., data of the (n+1)-th address is output.
- (3) When ACK signal 'LOW' after D0 is detected, and stop condition is not sent from master (μ -COM) side, the next address data can be read in succession.
- (4) Read cycle is ended by stop condition where 'H' is input to ACK signal after D0 and SDA signal goes from 'L' to 'H' while SCL signal is 'H'.
- (5) When 'H' is not input to ACK signal after D0, sequential read gets in, and the next data is output. Therefore, read command cycle cannot be ended. To end the read command cycle, be sure to input 'H' to ACK signal after D0, and the stop condition where SDA goes from 'L' to 'H' while SCL signal is 'H'.
- (6) Sequential read is ended by stop condition where 'H' is input to ACK signal after arbitrary D0 and SDA is asserted from 'L' to 'H' while SCL signal is 'H'.

Software Reset

Software reset is executed to avoid malfunction after power on and during command input. Software reset has several kinds and 3 kinds of them are shown in the figure below. (Refer to Figure 33(a), Figure 33(b), and Figure 33(c).) Within the dummy clock input area, the SDA bus is released ('H' by pull up) and ACK output and read data '0' (both 'L' level) may be output from EEPROM. Therefore, if 'H' is input forcibly, output may conflict and over current may flow, leading to instantaneous power failure of system power source or influence upon devices.

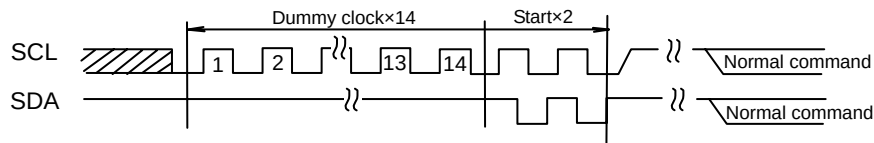


Figure 33-(a) The case of 14 dummy clock + START+START+ command input

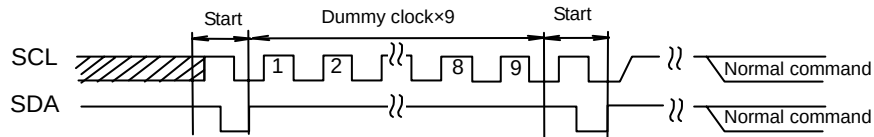


Figure 33-(b) The case of START + 9 dummy clocks + START+ command input

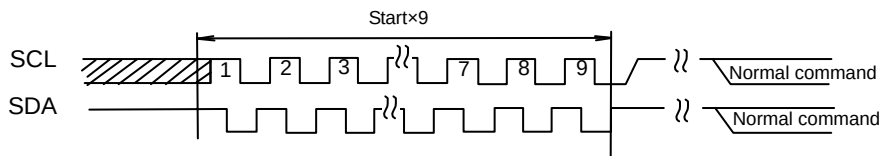


Figure 33-(c) START×9+ command input

* Start command from START input.

Acknowledge Polling

During internal write execution, all input commands are ignored, therefore ACK is not returned. During internal automatic write execution after write cycle input, next command (slave address) is sent. If the first ACK signal sends back 'L', then it means end of write operation, else 'H' is returned, which means writing is still in progress. By the use of acknowledge polling, next command can be executed without waiting for $t_{WR} = 5\text{ms}$.

To write continuously, $R/\overline{W} = 0$, then to carry out current read cycle after write, slave address with $R/\overline{W} = 1$ is sent. If ACK signal sends back 'L', and then execute word address input and data output and so forth.

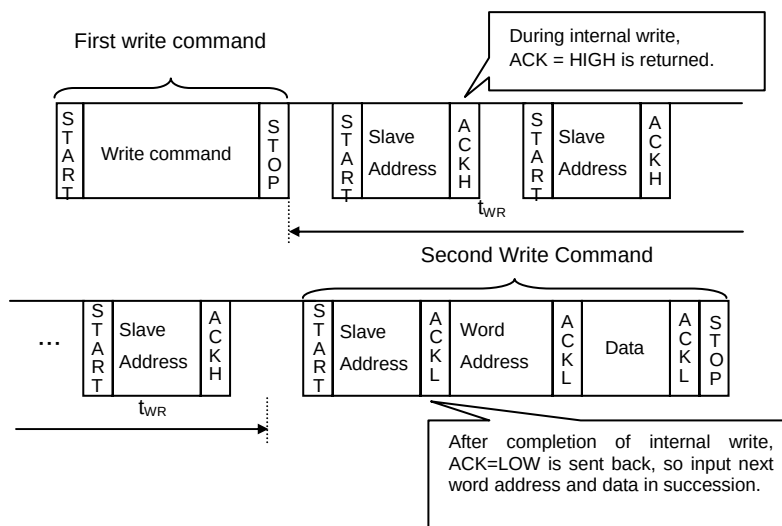


Figure 34. Case of Continuous Write by Acknowledge Polling

WP Valid Timing (Write Cancel)

WP is usually fixed to 'H' or 'L', but when WP is used to cancel write cycle and so forth, pay attention to the following WP valid timing. During write cycle execution, in cancel valid area, by setting WP='H', write cycle can be cancelled. In both byte write cycle and page write cycle, the area from the first start condition of command to the rise of clock to taken in D0 of data(in page write cycle, the first byte data) is cancel invalid area. WP input in this area becomes Don't care. Set the setup time to rise of D0 taken SCL 100ns or more. The area from the rise of SCL to take in D0 to input the stop condition is cancel valid area. And, after execution of forced end by WP, standby status gets in.

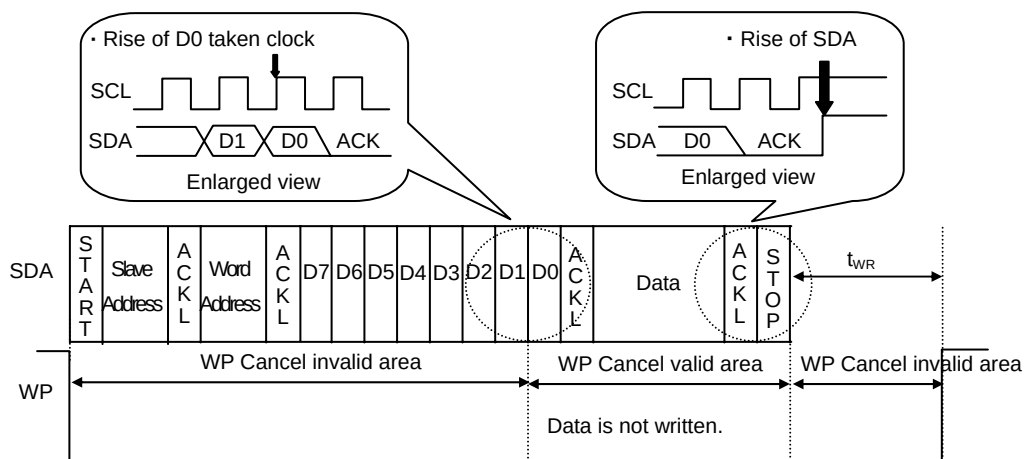


Figure 35. WP Valid Timing

Command Cancel by Start Condition and Stop Condition

During command input, by continuously inputting start condition and stop condition, command can be cancelled. (Figure 36) However, within ACK output area and during data read, SDA bus may output 'L'. In this case, start condition and stop condition cannot be input, so reset is not available. Therefore, execute software reset. When command is cancelled by start-stop condition during random read cycle, sequential read cycle, or current read cycle, internal setting address is not determined. Therefore, it is not possible to carry out current read cycle in succession. To carry out read cycle in succession, carry out random read cycle.

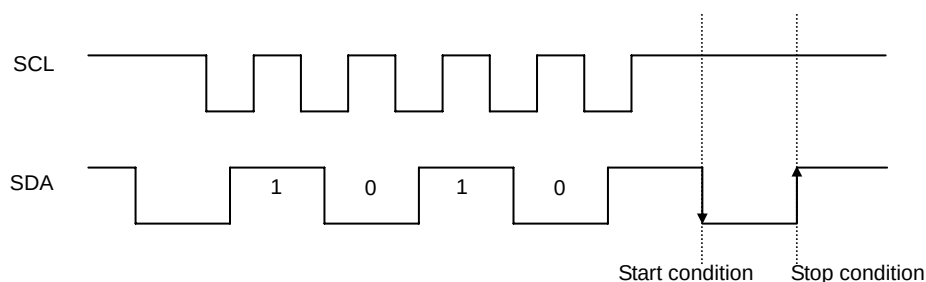


Figure 36. Case of Cancel by Start, Stop Condition during Slave Address Input

I/O Peripheral Circuit

1. Pull Up Resistance of SDA terminal

SDA is NMOS open drain, so it requires a pull up resistor. As for this resistance value (R_{PU}), select an appropriate value from microcontroller V_{IL} , I_L , and V_{OL} - I_{OL} characteristics of this IC. If R_{PU} is large, operating frequency is limited. The smaller the R_{PU} , the larger is the supply current (Read).

2. Maximum Value of R_{PU}

The maximum value of R_{PU} is determined by the following factors.

(1) SDA rise time to be determined by the capacitance (C_{BUS}) of bus line of R_{PU} and SDA should be t_R or lower.

Furthermore, AC timing should be satisfied even when SDA rise time is slow.

(2) The bus' electric potential (A) to be determined by the input current leak total (I_L) of the device connected to the bus with output of 'H' to the SDA line and R_{PU} should sufficiently secure the input 'H' level (V_{IH}) of microcontroller and EEPROM including recommended noise margin of $0.2V_{CC}$.

$$V_{CC} - I_L R_{PU} - 0.2V_{CC} \geq V_{IH}$$

$$\therefore R_{PU} \leq \frac{0.8V_{CC} - V_{IH}}{I_L}$$

Ex.) When $V_{CC} = 3V$, $I_L = 10\mu A$, $V_{IH} = 0.7 V_{CC}$,

From (2)

$$R_{PU} \leq \frac{0.8 \times 3 - 0.7 \times 3}{10 \times 10^{-6}} \\ \leq 300 [k\Omega]$$

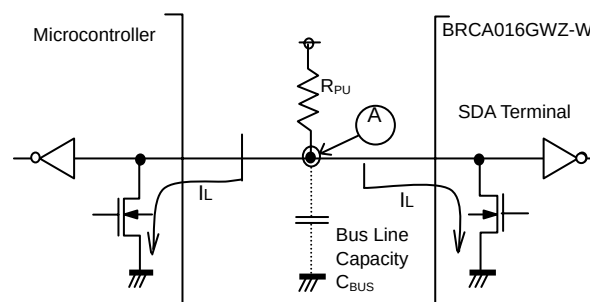


Figure 37. I/O Circuit Diagram

3. Minimum Value of R_{PU}

The minimum value of R_{PU} is determined by the following factors.

(1) When IC outputs LOW, it should be satisfied that $V_{OLMAX} = 0.4V$ and $I_{OLMAX} = 3mA$.

$$\frac{V_{CC} - V_{OL}}{R_{PU}} \leq I_{OL} \quad \therefore R_{PU} \geq \frac{V_{CC} - V_{OL}}{I_{OL}}$$

(2) $V_{OLMAX} = 0.4V$ should secure the input 'L' level (V_{IL}) of microcontroller and EEPROM including the recommended noise margin 0.1 of V_{CC} .

$$V_{OLMAX} \leq V_{IL} - 0.1 V_{CC}$$

Ex.) When $V_{CC} = 3V$, $V_{OL} = 0.4V$, $I_{OL} = 3mA$, microcontroller, EEPROM $V_{IL} = 0.3V_{CC}$

From (1)

$$R_{PU} \geq \frac{3 - 0.4}{3 \times 10^{-3}} \\ \geq 867 [\Omega]$$

And

$$V_{OL} = 0.4 [V]$$

$$V_{IL} = 0.3 \times 3$$

$$= 0.9 [V]$$

Therefore, the condition (2) is satisfied.

4. Pull-up Resistance of SCL Terminal

When SCL control is made at the CMOS output port, there is no need for a pull up resistor. But when there is a time where SCL becomes 'Hi-Z', add a pull up resistor. As for the pull up resistor value, one of several $k\Omega$ to several ten $k\Omega$ is recommended in consideration of drive performance of output port of microcontroller.

5. Process of WP Terminal

WP terminal is the terminal that prohibits and permits write in hardware manner. In 'H' status, only READ is available and WRITE of all address is prohibited. In case of 'L', both are available. If using as an ROM, it is recommended to connect it to pull up or V_{CC} . If using both READ and WRITE, control WP terminal or connect it to pull down or GND.

Cautions on Microcontroller Connection

1. R_S

In I²C BUS, it is recommended that SDA port is of open drain input/output. However, when using CMOS input / output of tri state to SDA port, insert a series resistance R_S between the pull up resistor R_{PU} and the SDA terminal of EEPROM. This is to control over current that may occur when PMOS of the microcontroller and NMOS of EEPROM are turned ON simultaneously. R_S also plays the role of protection the SDA terminal against surge. Therefore, even when SDA port is open drain input/output, R_S can be used.

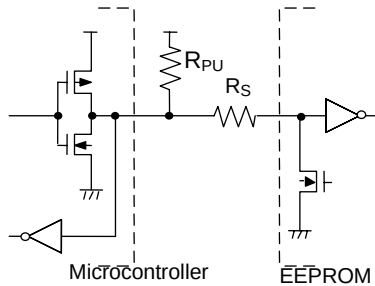


Figure 38. I/O Circuit Diagram

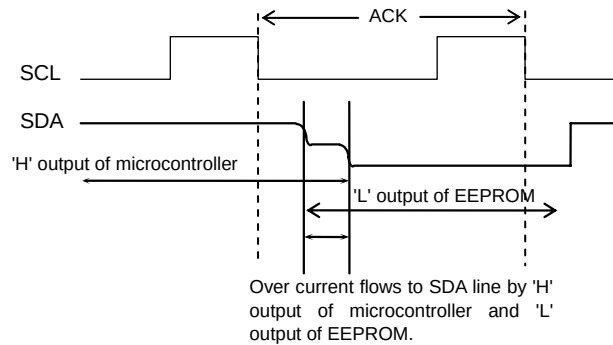


Figure 39. Input / Output Collision Timing

2. Maximum Value of R_S

The maximum value of R_S is determined by the following relations:

(1) SDA rise time to be determined by the capacitance (C_{BUS}) of bus line and R_{PU} of SDA should be t_R or lower.

Furthermore, AC timing should be satisfied even when SDA rise time is slow.

(2) The bus electric potential (A) to be determined by R_{PU} and R_S the moment when EEPROM outputs 'L' to SDA bus should sufficiently secure the input 'L' level (V_{IL}) of microcontroller including recommended noise margin of 0.1V_{CC}.

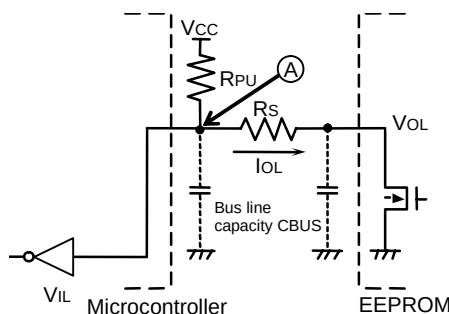


Figure 40. I/O Circuit Diagram

$$\frac{(V_{CC} - V_{OL}) \times R_S}{R_{PU} + R_S} + V_{OL} + 0.1V_{CC} \leq V_{IL}$$

$$\therefore R_S \leq \frac{V_{IL} - V_{OL} - 0.1V_{CC}}{1.1V_{CC} - V_{IL}} \times R_{PU}$$

Example) When $V_{CC}=3V$, $V_{IL}=0.3V_{CC}$, $V_{OL}=0.4V$, $R_{PU}=20k\Omega$,

$$\begin{aligned} \text{from (2), } R_S &\leq \frac{0.3 \times 3 - 0.4 - 0.1 \times 3}{1.1 \times 3 - 0.3 \times 3} \times 20 \times 10^3 \\ &\leq 1.67 [k\Omega] \end{aligned}$$

3. Minimum Value of R_S

The minimum value of R_S is determined by over current at bus collision. When over current flows, noises in power source line and instantaneous power failure of power source may occur. When allowable over current is defined as I , the following relation must be satisfied. Determine the allowable current in consideration of the impedance of power source line in set and so forth. Set the over current to EEPROM at 10mA or lower.

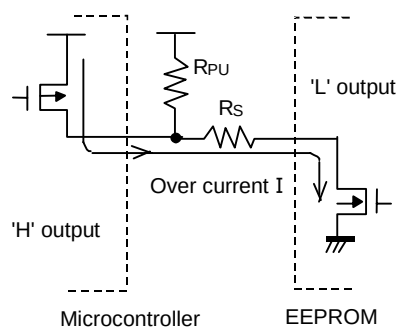


Figure 41. I/O Circuit Diagram

$$\frac{V_{CC}}{R_S} \leq I$$

$$\therefore R_S \geq \frac{V_{CC}}{I}$$

Example) When $V_{CC}=3V$, $I=10mA$

$$\begin{aligned} R_S &\geq \frac{3}{10 \times 10^{-3}} \\ &\geq 300 [\Omega] \end{aligned}$$

I/O Equivalence Circuit

1. Input (SCL, WP)

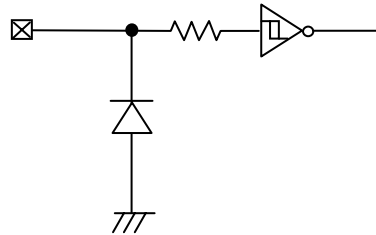


Figure 42. Input Pin Circuit Diagram

2. Input / Output (SDA)

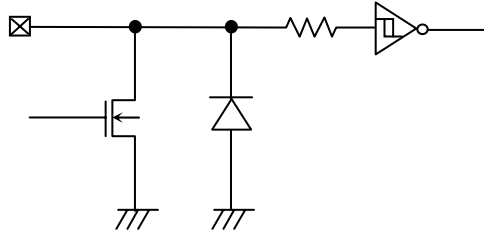


Figure 43. Input / Output Pin Circuit Diagram

Power-Up / Down Conditions

At power on, the IC's internal circuits may go through unstable low voltage area as the V_{CC} rises, making the IC's internal logic circuit not completely reset, hence, malfunction may occur. To prevent this, the IC is equipped with POR circuit and LVCC circuit. To assure the operation, observe the following conditions at power on.

1. Set SDA = 'H' and SCL = 'L' or 'H'
2. Start power source so as to satisfy the recommended conditions of t_R , t_{OFF} , and V_{bot} for operating POR circuit.

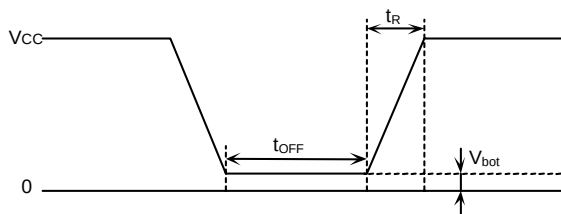


Figure 44. Rise Waveform Diagram

Recommended conditions of t_R , t_{OFF} , V_{bot}

t_R	t_{OFF}	V_{bot}
10ms or below	10ms or longer	0.3V or below
100ms or below	10ms or longer	0.2V or below

3. Set SDA and SCL so as not to become 'Hi-Z'.

When the above conditions 1 and 2 cannot be observed, take the following countermeasures.

- (1) In the case when the above condition 1 cannot be observed such that SDA becomes 'L' at power on.
→Control SCL and SDA as shown below, to make SCL and SDA, 'H' and 'H'.

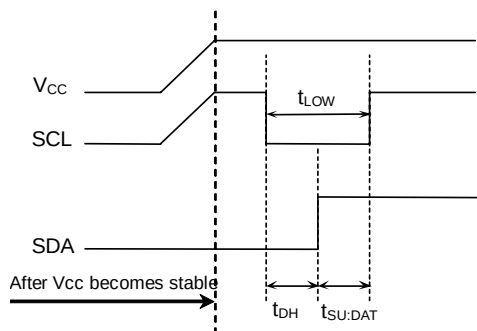


Figure 45. When SCL='H' and SDA='L'

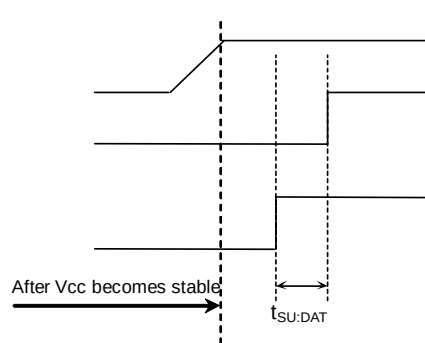


Figure 46. When SCL='H' and SDA='L'

- (2) In the case when the above condition 2 cannot be observed.
→After power source becomes stable, execute software reset(Page 15).
- (3) In the case when the above conditions 1 and 2 cannot be observed.
→Carry out (1), and then carry out (2).

Low Voltage Malfunction Prevention Function

LVCC circuit prevents data rewrite operation at low power and prevents write error. At LVCC voltage (Typ =1.2V) or below, data rewrite is prevented.

Noise Countermeasures

1. Bypass Capacitor

When noise or surge gets in the power source line, malfunction may occur, therefore, it is recommended to connect a bypass capacitor (0.1μF) between the IC's Vcc and GND pins. Connect the capacitor as close to the IC as possible. In addition, it is also recommended to attach a bypass capacitor between the board's Vcc and GND.

Operational Notes

1. Described numeric values and data are design representative values only and the values are not guaranteed.
2. We believe that the application circuit examples in this document are recommendable. However, in actual use, confirm characteristics further sufficiently. If changing the fixed number of external parts is desired, make your decision with sufficient margin in consideration of static characteristics, transient characteristics, and fluctuations of external parts and our LSI.
3. Absolute maximum ratings
If the absolute maximum ratings such as supply voltage, operating temperature range and so on are exceeded, LSI may be destroyed. Do not supply voltage or subject the IC to temperatures exceeding the absolute maximum ratings. In the case of fear of exceeding the absolute maximum ratings, take physical safety countermeasures such as adding fuses, and see to it that conditions exceeding the absolute maximum ratings should not be supplied to the LSI.
4. GND electric potential
Set the voltage of GND terminal lowest at any operating condition. Make sure that each terminal voltage is not lower than that of GND terminal.
5. Thermal design
Use a thermal design that allows for a sufficient margin by taking into account the permissible power dissipation (Pd) in actual operating conditions.
6. Short between pins and mounting errors
Be careful when mounting the IC on printed circuit boards. The IC may be damaged if it is mounted in a wrong orientation or if pins are shorted together. Short circuit may be caused by conductive particles caught between the pins.
7. Operating the IC in the presence of strong electromagnetic field may cause malfunction, therefore, evaluate design sufficiently.

Part Numbering

B R C A 0 1 6 G W Z - W

E 2

Part Number

Package

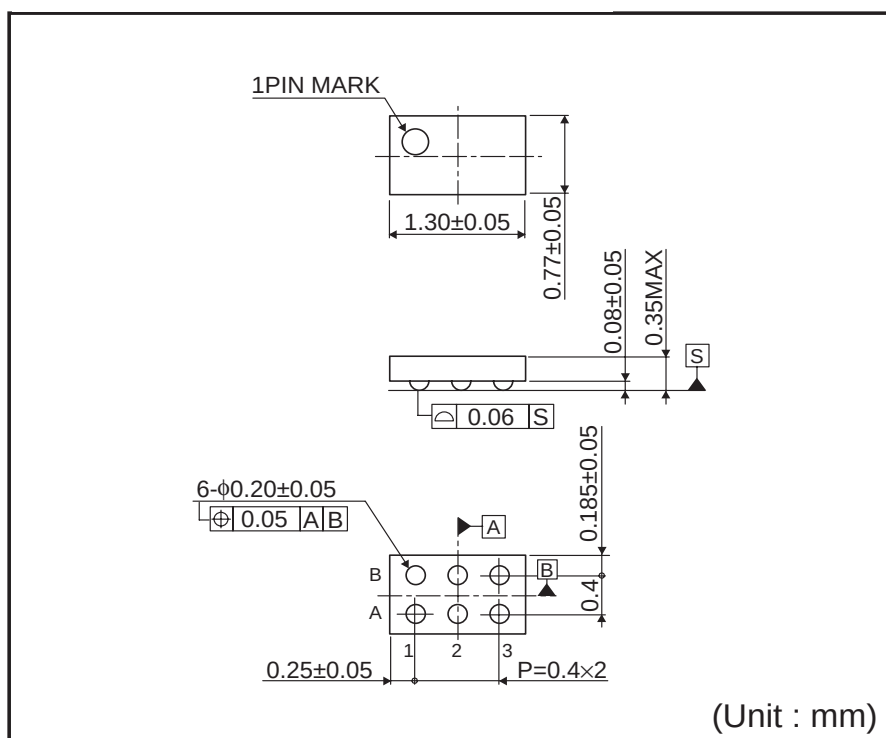
GWZ: UCSP30L1(BRCA016GWZ-W)

Packaging and Forming Specification

E2: Embossed tape and reel

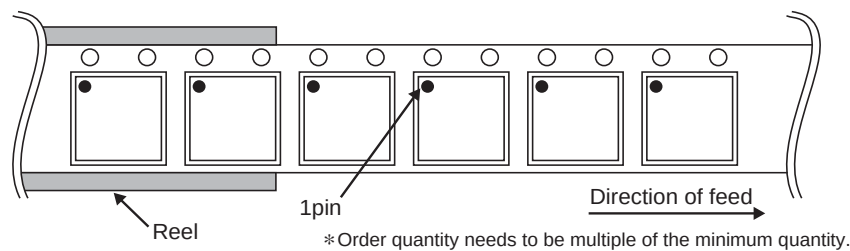
Physical Dimension Tape and Reel Information

UCSP30L1 (BRCA016GWZ-W)



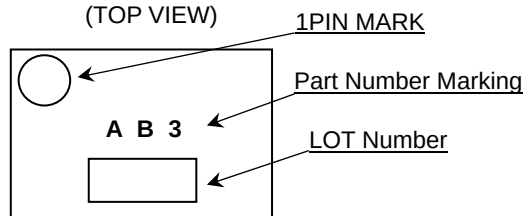
<Tape and Reel information>

Tape	Embossed carrier tape
Quantity	3000pcs
Direction of feed	E2 (The direction is the 1pin of product is at the upper left when you hold reel on the left hand and you pull out the tape on the right hand)



* Order quantity needs to be multiple of the minimum quantity.

Marking Diagram

UCSP30L1 (BRCA016GWZ-W)
(TOP VIEW)

Revision History

Date	Revision	Changes
5.Sep.2012	001	New Release
25.Feb.2013	002	Update some English words, sentences' descriptions, grammar and formatting. Update Figure 35. WP Valid Timing.

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
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- 6) In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse) is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7) De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
- 8) Confirm that operation temperature is within the specified range described in the product specification.
- 9) ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2) In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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- 1) If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

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 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- 2) Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3) Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
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